NSN 5961-01-383-3846

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-383-3846 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.130 inches and 0.150 inches **Overall Diameter:** Between 0.057 inches and 0.067 inches **Function For Which Designed:** Switching **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, instantaneous **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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